

ZXTN25040DFL 40V, SOT23, NPN low power transistor

Summary

 $BV_{CEX} > 130V$

 $BV_{CEO} > 40V$

 $BV_{ECO} > 6V$

 $I_{C(cont)} = 1.5A$

V_{CE(sat)} < 85mV @ 1A

 $R_{CE(sat)} = 59m\Omega$

 $P_{D} = 350 \text{mW}$

Complementary part number ZXTP25040DFL

Description

Advanced process capability has been used to achieve high current gain hold up making this device ideal for applications requiring high pulse currents.

Features

- · High peak current
- · Low saturation voltage
- 130V forward blocking voltage
- 6V reverse blocking voltage

Applications

- · MOSFET and IGBT gate driving
- · DC-DC conversion
- · LED driving
- · Interface between low voltage IC's and loads

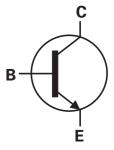
Ordering information

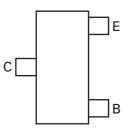
Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25040DFLTA	7	8	3000

Device marking

1B7







Pinout - top view

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	V _{CBO}	130	V
Collector-emitter voltage (forward blocking)	V _{CEX}	130	V
Collector-emitter voltage	V _{CEO}	40	V
Emitter-collector voltage (reverse blocking)	V _{ECO}	6	V
Emitter-base voltage	V _{EBO}	7	V
Continuous collector current ^(a)	I _C	1.5	Α
Base current	I _B	0.5	Α
Peak pulse current	I _{CM}	6	Α
Power dissipation at T _{amb} = 25°C ^(a)	P _D	350	mW
Linear derating factor		2.8	mW/°C
Operating and storage temperature range	T _j , T _{stg}	-55 to 150	°C

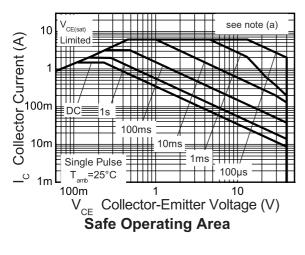
Thermal resistance

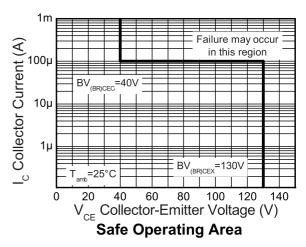
Parameter	Symbol	Limit	Unit
Junction to ambient ^(a)	R_{\ThetaJA}	357	°C/W

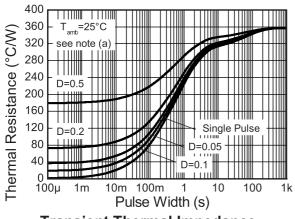
NOTES:

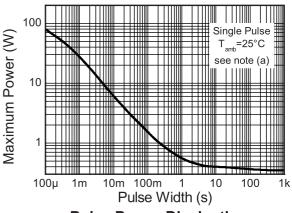
⁽a) For a device surface mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

Characteristics

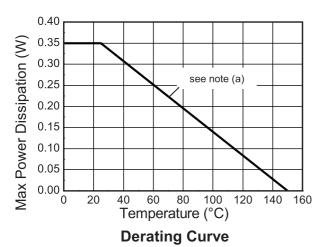








Transient Thermal Impedance



Pulse Power Dissipation

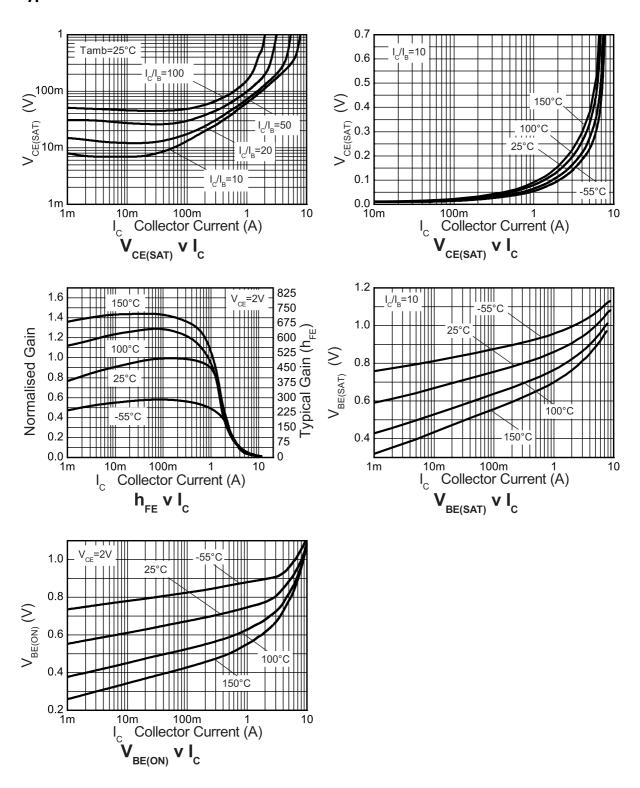
Electrical characteristics (at $T_{amb} = 25$ °C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CBO}	130	170		V	$I_C = 100 \mu A$
Collector-emitter breakdown voltage (forward blocking)	BV _{CEX}	130	170		V	I_C = 100μA; R_{BE} < 1k Ω or -1V < V_{BE} < 0.25V
Collector-emitter breakdown voltage (base open)	BV _{CEO}	40	63		V	I _C = 10mA (*)
Emitter-base breakdown voltage	BV _{EBO}	7	8.3		V	I _E = 100μA
Emitter-collector breakdown voltage (reverse blocking)	BV _{ECX}	6	7.4		V	$I_E = 100 \mu A$, $R_{BC} < 1 k \Omega$ or $0.25 V > V_{BC} > -0.25 V$
Emitter-collector breakdown voltage (base open)	BV _{ECO}	6	7.4		V	$I_E = 100 \mu A$,
Collector cut-off current	I _{CBO}		<1	50 20	nA μA	$V_{CB} = 100V$ $V_{CB} = 100V$, $T_{amb} = 100$ °C
Collector emitter cut-off current	I _{CEX}		<1	100	nA	$V_{CE} = 100V; R_{BE} < 1k\Omega \text{ or}$ -1V < $V_{BE} < 0.25V$
Emitter cut-off current	I _{EBO}		<1	50	nA	V _{EB} = 5.6V
Collector-emitter saturation	V _{CE(sat)}		35	50	mV	$I_C = 0.5A$, $I_B = 50mA^{(*)}$
voltage			60	80	mV	$I_C = 0.5A, I_B = 10mA^{(*)}$
			70	85	mV	I _C = 1A, I _B = 100mA
			145	185	mV	$I_C = 1.5A$, $I_B = 30mA^{(*)}$
			235	285	mV	$I_C = 4A$, $I_B = 400 \text{mA}^{(*)}$
Base-emitter saturation voltage	V _{BE(sat)}		840	950	mV	I _C = 1.5A, I _B = 30mA ^(*)
Base-emitter turn-on voltage	V _{BE(on)}		770	850	mV	$I_C = 1.5A, V_{CE} = 2V^{(*)}$
Static forward current	h _{FE}	300	450	900		$I_C = 10 \text{mA}, V_{CE} = 2V^{(*)}$
transfer ratio		300	400			$I_C = 1A, V_{CE} = 2V^{(*)}$
		170	250			$I_C = 1.5A, V_{CE} = 2V^{(*)}$
		25	40			$I_C = 4A$, $V_{CE} = 2V^{(*)}$
Transition frequency	f _T		190		MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Output capacitance	C _{obo}		11.7	20	pF	V _{CB} = 10V, f = 1MHz ^(*)
Delay time	t _(d)		64		ns	V _{CC} = 10V,
Rise time	t _(r)		108		ns	$I_C = 1A$,
Storage time	t _(s)		428		ns	$I_{B1} = I_{B2} = 10 \text{mA}.$
Fall time	t _(f)		130		ns	

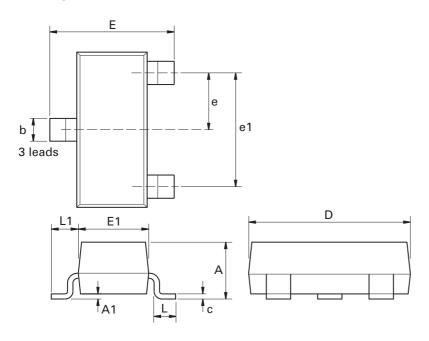
NOTES:

(*) Measured under pulsed conditions. Pulse width $\leq 300 \mu s$; duty cycle $\leq 2\%$.

Typical characteristics



Package outline - SOT23



Dim.	Millin	neters	Inc	hes	Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
Α	-	1.12	-	0.044	e1	1.90	NOM	0.075	NOM
A1	0.01	0.10	0.0004	0.004	Е	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
С	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95	NOM	0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Intentionally left blank

Definitions

Product change

Zetex Semiconductors reserves the right to alter, without notice, specifications, design, price or conditions of supply of any product or service. Customers are solely responsible for obtaining the latest relevant information before placing orders.

Applications disclaimer

The circuits in this design/application note are offered as design ideas. It is the responsibility of the user to ensure that the circuit is fit for the user's application and meets with the user's requirements. No representation or warranty is given and no liability whatsoever is assumed by Zetex with respect to the accuracy or use of such information, or infringement of patents or other intellectual property rights arising from such use or otherwise. Zetex does not assume any legal responsibility or will not be held legally liable (whether in contract, tort (including negligence), breach of statutory duty, restriction or otherwise) for any damages, loss of profit, business, contract, opportunity or consequential loss in the use of these circuit applications, under any circumstances.

Life support

Zetex products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Zetex Semiconductors plc. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body

_

- 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Reproduction

The product specifications contained in this publication are issued to provide outline information only which (unless agreed by the company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contract or be regarded as a representation relating to the products or services concerned.

Terms and Conditions

All products are sold subjects to Zetex' terms and conditions of sale, and this disclaimer (save in the event of a conflict between the two when the terms of the contract shall prevail) according to region, supplied at the time of order acknowledgement.

For the latest information on technology, delivery terms and conditions and prices, please contact your nearest Zetex sales office.

Quality of product

Zetex is an ISO 9001 and TS16949 certified semiconductor manufacturer.

To ensure quality of service and products we strongly advise the purchase of parts directly from Zetex Semiconductors or one of our regionally authorized distributors. For a complete listing of authorized distributors please visit: www.zetex.com/salesnetwork

Zetex Semiconductors does not warrant or accept any liability whatsoever in respect of any parts purchased through unauthorized sales channels.

ESD (Electrostatic discharge)

Semiconductor devices are susceptible to damage by ESD. Suitable precautions should be taken when handling and transporting devices. The possible damage to devices depends on the circumstances of the handling and transporting, and the nature of the device. The extent of damage can vary from immediate functional or parametric malfunction to degradation of function or performance in use over time. Devices suspected of being affected should be replaced.

Green compliance

Zetex Semiconductors is committed to environmental excellence in all aspects of its operations which includes meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Zetex components are compliant with the RoHS directive, and through this it is supporting its customers in their compliance with WEEE and ELV directives.

Product status key:	
"Preview"	Future device intended for production at some point. Samples may be available
"Active"	Product status recommended for new designs
"Last time buy (LTB)"	Device will be discontinued and last time buy period and delivery is in effect
"Not recommended for new designs"	Device is still in production to support existing designs and production
"Obsolete"	Production has been discontinued
Datasheet status key:	
"Draft version"	This term denotes a very early datasheet version and contains highly provisional information, which may change in any manner without notice.
"Provisional version"	This term denotes a pre-release datasheet. It provides a clear indication of anticipated performance. However, changes to the test conditions and specifications may occur, at any time and without notice.
"Issue"	This term denotes an issued datasheet containing finalized specifications. However, changes to specifications may occur, at any time and without notice.

Zetex sales offices

Europe	Americas	Asia Pacific	Corporate Headquarters
Zetex GmbH	Zetex Inc	Zetex (Asia Ltd)	Zetex Semiconductors plc
Kustermann-park	700 Veterans Memorial Highway	3701-04 Metroplaza Tower 1	Zetex Technology Park, Chadderton
Balanstraße 59	Hauppauge, NY 11788	Hing Fong Road, Kwai Fong	Oldham, OL9 9LL
D-81541 München Germany	USA	Hong Kong	United Kingdom
Telefon: (49) 89 45 49 49 0	Telephone: (1) 631 360 2222	Telephone: (852) 26100 611	Telephone: (44) 161 622 4444
Fax: (49) 89 45 49 49 49	Fax: (1) 631 360 8222	Fax: (852) 24250 494	Fax: (44) 161 622 4446
europe.sales@zetex.com	usa.sales@zetex.com	asia.sales@zetex.com	hq@zetex.com

© 2007 Published by Zetex Semiconductors plc

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Inc.:
ZXTN25040DFLTA